## HiPerFET ${ }^{\text {TM }}$ <br> Power MOSFETs Q-CLASS

## Single MOSFET Die

N-ChannelEnhancement Mode
Avalanche Rated, Low Qg,
High dV/dt, Low $t_{r r}$
IXFK 27N80Q
IXFX 27N80Q


| Symbol | Test Conditions | Maximum Ratings |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {DSs }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | 800 | V |
| $V_{\text {DGR }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C} ; \mathrm{R}_{\mathrm{GS}}=1 \mathrm{M} \Omega$ | 800 | V |
| $\mathrm{V}_{\text {gs }}$ | Continuous | $\pm 20$ | V |
| $\mathrm{V}_{\text {GSM }}$ | Transient | $\pm 30$ | V |
| $\mathrm{I}_{\mathrm{D} 25}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 27 | A |
| $\mathrm{I}_{\mathrm{DM}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$, pulse width limited by $\mathrm{T}_{\text {JM }}$ | 108 | A |
| $\mathrm{I}_{\text {AR }}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 27 | A |
| $\mathrm{E}_{\text {AR }}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 60 | mJ |
| $\mathrm{E}_{\text {AS }}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 2.5 | J |
| dv/dt |  | 5 | V/ns |
| $\mathrm{P}_{\mathrm{D}}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 500 | W |
| $\mathrm{T}_{\text {J }}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {Jм }}$ |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | 1.6 mm (0.063 in.) from case for 10 s | 300 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{M}_{\mathrm{d}}$ | Mounting torque TO-264 | 0.4/6 | Nm/lb.in. |
| Weight | PLUS 247 |  | 6 g |
|  | TO-264 |  | 10 g |


| Symbol | Test Conditions | Characteristic Values <br> ( $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, unless otherwise specified) min. typ. max. |  |  |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {DSS }}$ | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=1 \mathrm{~mA}$ | 800 |  | V |
| $\mathrm{V}_{\mathrm{GS}(\mathrm{h})}$ | $\mathrm{V}_{\mathrm{DS}}=\mathrm{V}_{\mathrm{GS}}, \mathrm{I}_{\mathrm{D}}=4 \mathrm{~mA}$ | 2.0 |  | 4.5 V |
| $\mathrm{I}_{\text {GSS }}$ | $\mathrm{V}_{\mathrm{GS}}= \pm 20 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0$ |  |  | $\pm 100 \mathrm{nA}$ |
| $\mathrm{I}_{\text {DS }}$ | $\begin{aligned} & V_{D S}=V_{D S S} \\ & V_{G S}=0 V \end{aligned}$ | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  | $\begin{array}{r} 100 \mu \mathrm{~A} \\ 2 \mathrm{~mA} \end{array}$ |
| $\mathrm{R}_{\mathrm{DS}(\mathrm{on})}$ | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=0.5 \cdot \mathrm{I}_{\mathrm{D} 25}$ <br> Note 1 |  |  | $320 \mathrm{~m} \Omega$ |


$t_{r r} \leq 250$ ns

$\mathrm{G}=$ Gate
S = Source
D = Drain
TAB = Drain

## Features

- IXYS advanced low $Q_{q}$ process
- Low gate charge and capacitances
- easier to drive
- faster switching
- International standard packages
- Low $\mathrm{R}_{\text {DS (on) }}$
- Rated for unclamped Inductive load switching (UIS) rated
- Molding epoxies meet UL 94 V-0 flammability classification


## Applications

- DC-DC converters
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- AC motor control
- Temperature and lighting controls


## Advantages

- PLUS $247^{T M}$ package for clip or spring mounting
- Space savings
- High power density


## Symbol TestConditions

Characteristic Values ( $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, unless otherwise specified) min. ${ }^{\text {typ. }}$ max.

| $\mathrm{g}_{\text {ts }}$ | $V_{\text {DS }}$ | $=10 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=0.5 \cdot \mathrm{l}_{\text {225 }}$ | Note 1 | 20 | 27 |  | S |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{\text {iss }}$ | $)$ | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=25 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  |  | 7600 |  | pF |
| $\mathrm{C}_{\text {oss }}$ |  |  |  |  | 750 |  | pF |
| $\mathrm{C}_{\text {rss }}$ | ) |  |  |  | 120 |  | pF |
| $\mathrm{t}_{\text {d(on) }}$ | ) | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0.5 \cdot \mathrm{~V}_{\mathrm{DSS}}, \mathrm{I}_{\mathrm{D}}=0.5 \cdot \mathrm{l}_{\mathrm{D} 25}$$\mathrm{R}_{\mathrm{G}}=1 \Omega$ (External), |  |  | 20 |  | ns |
| $\mathrm{t}_{\mathrm{r}}$ |  |  |  |  | 28 |  | ns |
| $\mathrm{t}_{\text {doff) }}$ |  |  |  |  | 50 |  | ns |
| $\mathrm{t}_{4}$ |  |  |  |  | 13 |  | ns |
| $\mathbf{Q}_{\text {g(on) }}$ |  | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0.5 \cdot \mathrm{~V}_{\mathrm{DSS}}, \mathrm{I}_{\mathrm{D}}=0.5 \cdot \mathrm{I}_{\mathrm{D} 25}$ |  |  | 170 |  | nc |
| $\mathrm{Q}_{\mathrm{gs}}$ | \} |  |  |  | 47 |  | nC |
| $\mathrm{Q}_{\mathrm{gd}}$ | , |  |  |  | 65 |  | nC |
| $\mathrm{R}_{\text {thuc }}$ |  |  |  |  |  | 0.26 | KW |
| $\mathrm{R}_{\text {trck }}$ |  |  |  |  | 0.15 |  | KW |

## Source-Drain Diode

Characteristic Values ( $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$, unless otherwise specified)

| Symbol | Test Conditions | min. | typ. | max. |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\text {s }}$ | $\mathrm{V}_{\text {GS }}=0 \mathrm{~V}$ |  |  | 27 | A |
| $\mathrm{I}_{\text {sm }}$ | Repetitive; pulse width limited by $\mathrm{T}_{\mathrm{JM}}$ |  |  | 108 | A |
| $\mathrm{v}_{\text {so }}$ | $\mathrm{I}_{\mathrm{F}}=\mathrm{I}_{\mathrm{S}}, \mathrm{V}_{\text {GS }}=0 \mathrm{~V}$, Note 1 |  |  | 1.5 | v |
| $t_{r r}$ $\mathrm{Q}_{\mathrm{RM}}$ $I_{\text {RM }}$ | $\} I_{F}=I_{s},-\mathrm{di} / \mathrm{dt}=100 \mathrm{~A} / \mathrm{\mu s}, \mathrm{~V}_{\mathrm{R}}=100 \mathrm{~V}$ |  | 1.3 8 | 250 | ns $\mu \mathrm{C}$ A |

Note: 1. Pulse test, $\mathrm{t} \leq 300 \mu \mathrm{~s}$, duty cycle $\mathrm{d} \leq 2 \%$


TO-264 AA Outline


| Dim. | Millimeter |  | Inches |  |
| :--- | :---: | :---: | :---: | :---: |
|  | Min. | Max. | Min. | Max. |
| A | 4.82 | 5.13 | .190 | .202 |
| A1 | 2.54 | 2.89 | .100 | .114 |
| A2 | 2.00 | 2.10 | .079 | .083 |
| b | 1.12 | 1.42 | .044 | .056 |
| b1 | 2.39 | 2.69 | .094 | .106 |
| b2 | 2.90 | 3.09 | .114 | .122 |
| c | 0.53 | 0.83 | .021 | .033 |
| D | 25.91 | 26.16 | 1.020 | 1.030 |
| E | 19.81 | 19.96 | .780 | .786 |
| e | 5.46 | BSC | .215 BSC |  |
| J | 0.00 | 0.25 | .000 | .010 |
| K | 0.00 | 0.25 | .000 | .010 |
| L | 20.32 | 20.83 | .800 | .820 |
| L1 | 2.29 | 2.59 | .090 | .102 |
| P | 3.17 | 3.66 | .125 | .144 |
| Q | 6.07 | 6.27 | .239 | .247 |
| Q1 | 8.38 | 8.69 | .330 | .342 |
| R | 3.81 | 4.32 | .150 | .170 |
| R1 | 1.78 | 2.29 | .070 | .090 |
| S | 6.04 | 6.30 | .238 | .248 |
| T | 1.57 | 1.83 | .062 | .072 |

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